Sunday - August 25, 2019

	/
16:00-18:00	Registration
18:00-20:00	Official Welcome

Monday - August 26, 2019

Monday - August 26, 2019					
A Session	09:00	Opening Ceremony			
Chair:	09:10	PL: Vladimir Chernysh (Russia) - Interaction of gas cluster ions with			
Gennady		solids: experiment and computer simulations			
Remnev	09:55	PL: Liangting Sun (China) - Low energy heavy ion accelerator facilities in			
		IMP for material radiation research			
	10:40	Coffee-break			
A Session 1:	11:00	I 1-1 David Tetelbaum (Russia)			
Ion Beam		Ion-beam modification of Si and SiO ₂ /Si structures for the development of			
Processing of		light-emitting silicon-based devices			
Materials	11:30	I 1-2 Gennady Remnev (Russia)			
Chair:		High-power pulsed ion accelerators and their practical application			
Vladimir	12:00	I 1-3 Noriaki Matsunami (Japan)			
Chernysh		Modifications of WNO _x films by keV D and H ions			
	12:30	O 1-1 Jerzy Żuk (Poland)			
		Structure and optical properties of ZnO-SiO ₂ nanocomposite synthesized by			
		high-fluence implantation and subsequent annealing			
	12:50	Lunch			
Chair:	14:00	O 1-2 Melanie Clozel* (Poland)			
Liangting		Investigation of the nanomechanical properties of ion-irradiated ferritic-			
Sun		martensitic steels with different chemical compositions using			
		nanoindentation			
	14:20	O 1-3 Xiaonan Zhang* (P.R. China)			
		The structural thermal stability of the Fe ₈₀ Si ₇ B ₁₃ alloys under the irradiation			
		of high-intensity pulsed ion beam			
	14:40	O 1-4 Irina Kurzina (Russia)			
		Surface property modification of biocompatible polymer materials by ion			
		implantation and electron beam treatment			
	15:00	O 1-5 Krzysztof Siemek (Poland)			
		Positron annihilation studies of ultra-fine grain Ti irradiated with 167 MeV			
		Xe ²⁶ + heavy ions			
	15:20	O 1-6 Andrzej Olejniczak (Russia)			
		Modification of graphene oxide films with swift heavy ions: changes in the			
	15.40	electrical and structural properties			
	15:40	O 1-7 Ruslan Rymzhanov* (Russia)			
	16.00	Picosecond surface kinetics of swift heavy ion irradiated insulators			
	16:00	Coffee-break			
D (16:30	Photographing			
Poster	16:40	P 1-1 – P 1-40			
Session 1:	18:00				
ion ocam					
processing of					
materials					
Chair:					
Irina Kurzina					
Kurzina					

Tuesday - August 27, 2019

Tuesday - August 27, 2019							
A Session Chair:	09:00	PL: Andre Anders (Ger	many) - Plasma	a physics	of sputtering magnetrons		
Wolfgang	09:45	PL: Jindrich Musil (Czech Republic) - Advanced hard nanocoatings					
Ensinger		deposited by magnetron	sputtering: rol	e of ener	gy		
	10:30	Coffee-break					
A Session 2:	11:00	I 2-1 Koumei Baba	B Session 1:	11:00	I 1-4 Luc Pichon		
Ion-assisted		(Japan)	Ion Beam		(France)		
coating deposition		Plasma source ion implantation: from	Processing of Materials		About low temperature nitriding mechanism of		
Chair:		research setups to	Chair:		FCC-nickel-based alloys		
Koumei		large-scale industrial	Luc Pichon		by plasma immersion		
Baba		applications					
	11:30	I 2-2 Valery		11:30	I 1-5 Alexander		
		Krivibokov (Russia)			Ryabchikov (Russia)		
		Metal coatings			Progress in high intensity, low ion energy		
		deposition using hot			implantation method		
		target magnetrons			development		
	12:00	O 2-1 Tiancheng		12:00	O 1-8 Tran Van Phuc*		
		Wang* (P.R. China)			(Vietnam)		
		Magnetic field induced ion motion in			Investigations of elemental depth distribution and		
		vacuum arc deposition			chemical compositions in		
		for interior surfaces			the multilayer structures of		
					TiO ₂ /SiO ₂ /Si after ion		
	12.20	0.2.2.41		12.20	irradiation		
	12:20	O 2-2 Alexey Vereschaka (Russia)		12:20	O 1-9 Haowen Zhong (P.R. China)		
		Study of specifics in			The influence of metal		
		nanolayer composite			surface topography on		
		coating formation			ablation behavior during		
		using filtered cathodic			intense pulsed ion beam		
		vacuum arc deposition			irradiation		
	12:40	(FCVAD) technology Lunch					
A Session 2:	14:00	O 2-3 Hui Sun*	B Session 1:	14:00	O 1-10 Xianxiu Mei		
Ion-assisted		(P.R. China)	Ion Beam		(P.R. China)		
coating		Microstructures and	Processing		Damage behaviour of		
deposition		optoelectronic	of Materials		Fe-based metallic glass		
Chair: Andre		properties of NiO films deposited by	Chair: David		under He and H ions irradiation		
Anders		high power impulse	Tetelbaum		mauration		
		magnetron sputtering	100104411				
	14:20	O 2-4 Dmitry		14:20	O 1-11 Samit Kumar		
		Sidelev* (Russia)			Mandal (India)		
		Nickel and chromium			Critical usage of erbium		
		deposition by hot target magnetron			for radiation shielding for advanced applications		
		sputtering			advanced applications		

	14:40	O 2-5 Olga Krysina	14:40	O 1-12 Sunmog Yeo*
		(Russia)		(S.Korea)
		Influence of		Ion bombardment effects
		ion-plasma assistance		on polycarbonate
		on the composition,		T J J
		structure and		
		properties of		
		wear-resistance nitride		
		coatings		
	15:00	O 2-6 Vladimir	15:00	O 1-13 Elke Wendler
		Denisov* (Russia)		(Germany)
		Generation of beam		Structural and optical
		plasma formations in a		properties of Si
		non-self-sustained		hyperdoped with Te by ion
		glow discharge with a		implantation and pulsed
		hollow cathode for ion		laser annealing
		nitriding of steels		
	15:20	O 2-7 Yury Sharkeev	15:20	O 1-14 Haowen Zhong
		(Russia)		(P.R. China)
		RF-magnetron		Crater evolution on
		sputtering of calcium		surface morphology of
		phosphates for		metallic material under
		medical implants:		intense pulsed ion beam
		structure and		irradiation
	15.10	properties	15.10	
	15:40	O 2-8 Oksana	15:40	O 1-15 Valeria Kostenko*
		Bytsenko (Russia)		(Russia)
		Microstructure, fatigue		Surface modification of
		strength and erosion resistance of		ZrO ₂ -3Y ₂ O ₃ ceramics with continuous Ar ⁺ ion beams
		MAX-phase embedded		continuous Ai Ion beams
		Ti-Si-B nanostructured		
		coatings on Ti-6Al-4V		
	16:00	O 2-9 Yulei Yang*	16:00	O 1-16 Vikas Kumar*
	10.00	(P.R. China)	10.00	(India)
		Influence of combined		Swift heavy ion beam
		nitrogen implantation		induced modifications in
		on adhesion strength		structural, optical,
		of TiAlN film on TiAl		chemical and
		alloy		morphological properties
				of SnO ₂ -TiO ₂
				nanocomposite thin films
	16:20	Coffee-break	 	
Poster	16:50	P 2-1-P 2-11	 	
Session 2:	_			
Ion-assisted	18:00			
coating				
deposition				
Chair:				
Anatoly				
Kupchishin				

Wednesday - August 28, 2019

		t 28, 2019	1		
A Session 4: Defect engineering, nano-science and technology Chair: Xiaoyun Le	09:00	I 4-1 Wolfgang Ensinger (Germany) Damage tracks of high energy ions in polymers and their use for fabricating 1-dimensional nanostructures I 4-3 Vladimir Uglov (Belarus) Tolerance of multilayered systems MeN/Si ₃ N ₄ (Me=Cr, Zr, Al) to radiation erosion	B Session 6: Biomedical and industrial applications Chair: Dong-Hai Zhang	09:00	I 6-1 Alexander Tikhonov (Kazakhstan) New high-current pulsed ion accelerator facility INURA at Nazarbayev University: first results and new opportunities for advanced materials and nanoscience I 6-2 Jae-Sung Kim (Korea) Nanoscale pattern formation at surfaces in unconventional formats
	10:00	O 4-1 Pawel Horodek (Poland) Positron annihilation studies of irradiation induced defects in gold and niobium		10:00	I 6-3 Feng Liu (P.R. China) Ultra-high selective and permeable ion sieve fabricated with irradiated polymer membranes
	10:30		Coffee-	.hreak	
A Session 4: Defect engineering, nano-science and technology Chair:	11:00	O 4-2 Miroslaw Kulik (Russia) Studies of InAs formation in indium implanted GaAs exposed to annealing	B Session 6: Biomedical and industrial applications Chair: Valery	11:00	O 6-1 Mikhail Slobodyan (Russia) Effect of surface modification of Zr-1%Nb alloy on corrosion resistance and high- temperature oxidation
Alexander Ryabchikov	11:20	O 4-3 Victor Paperny (Russia) Fabrication of metal-dielectric nanocomposites using a table-top ion implanter O 4-4 Jialong He (P.R. China) Preliminary experimental study on the effects of low- energy titanium ion beam irradiation on secondary electron emission characteristics of metal materials	Krivibokov	11:20	O 6-2 Alexey Remnev (Japan) Chemical and physical aspects of ion beam sharpening of medical needle O 6-3 Andrey Solovyev (Russia) Reactive dual deep oscillation magnetron sputtering of Al ₂ O ₃ films

	12:00			12:00	O 6-4 Yunhan Ling (P.R. China) Surface chemistry and electronic structure of passive film on N18 zircaloy with krypton irradiation
	12:20	Lunch			
A Session 5: New	14:00	I 5-	1 Tomohiro Kor-driven neutro		(Japan) for material analysis
accelerator systems and tools for materials	14:30	Some reflections or	I 5-2 Ian Bro	`	A) am surface modification
research Chair: Efim Oks	15:00	O 5-1 Gaolong Zhang (P.R. China) The test of silicon strip detector for heavy-ion nuclear reaction	B Session 6: Biomedical and industrial applications Chair: Jae-Sung	15:00	O 6-6 Vyacheslav Chudinov* (Russia) Medical polyurethane modified by ion beam
	15:20	O 5-2 Vladislav Ryzhkov (Russia) Radioactivation control of energy and number of protons and deuterons collectively accelerated in Luce diodes	Kim	15:20	O 6-7 Gulsharat Baigonakova* (Russia) Blood platelets adhesion to an intermetallic coating made by SHS using magnetron sputtering Ti-Ni-Ti nano-laminate
	15:40			15:40	O 6-8 Pavel Maryin* (Russia) Time-stable wetting effect of plasma-treated biodegradable scaffolds covered with graphene oxide
	16:00	Coffee-break			

Poster	16:30	P 3-1- P 3-12	Poster	16:30	P 5-1-P 5-7
Session 3:	_		Session 5:	_	
Basic	18:00		New	18:00	
mechanisms,			accelerator		
theory and			systems and		
fundamental			tools for		
Chair:			materials		
Alexander			research		
Ligachev			Chair:		
			Alexander		
			Ligachev		
Poster		P 4-1-P 4-17	Poster		P 6-1-P 6-5
Session 4:			Session 6:		
Defect			Biomedical		
engineering,			and		
nano-science			industrial		
and technology			applications		
Chair:			Chair:		
Alexander			Alexander		
Ligachev			Ligachev		

Thursday - August 29, 2019

Thursday - A	ugust 2	29, 2019		•	
A Session 3:	09:00	I 3-1 Yan Sha	B Session 2:	09:00	I 2-3 Xiubo Tian
Basic		(P.R. China)	Ion-assisted		(P.R. China)
mechanisms,		Intense pulsed ion	coating		Pulsed high-power
theory and		beam applications on	deposition		discharge and arc for
fundamental		metals modification	Chair:		deposition of carbon
Chair:		and test	Xiubo Tian		based films
Yan Sha,	09:30	I 3-2 Anatoliy		09:30	I 2-4 Efim Oks
Gennady	07.50	Kupchishin		07.50	(Russia)
Remnev		(Kazakhstan)			Generation of «unusual»
Kenniev		Computer modeling of			ion beams based on
		pka energy spectra			discharge systems of
		and concentration of			vacuum arc and hollow
		vacancy clusters			cathode glow
		irradiated by light ions		10.00	
	10:00	O 3-1 Wei Zhao		10:00	O 2-10 Konstantin
		(P.R. China)			Prosolov* (Russia)
		Simulation studies on			Effect of glancing angle
		secondary electron			deposition to the
		emission			morphology of calcium
		characteristics of			phosphate thin coatings
		metal materials			
		radiated by ions of the			
		order of 100 keV			
	10:20	O 3-2 Vladimir		10:20	O 2-11 Hongfei Shang*
	10.20	Ovchinnikov (Russia)		10.20	(P.R. China)
		The law of			Preparation, properties
		independence of the			and application of
		emission spectra of			composite microparticles
		metal targets from			composite interoparticles
		energy and the mass			
	10.40	of implanted ions			
A C	10:40	Coffee-break		1	
A Session 3:	11:10	O 3-3 Mikołaj			
Basic		Gołuński* (Poland)			
mechanisms,		Molecular dynamics			
theory and		of free-standing			
fundamental		graphene bombarded			
Chair:		with keV Ar _n clusters			
Vladimir	11:30	O 3-4 Dong-Hai			
Uglov		Zhang (P.R. China)			
		Fragmentation of			
		carbon on elemental			
		targets at 290 A MeV			
	11:50	O 3-5 Michał Kański*			
		(Poland)			
		Effect of the impact			
		angle on the angular			
		distributions of β-			
		carotene sputtered by			
		15keV Ar ₂₀₀₀			
		1010 1 111 2000			
				<u> </u>	

	12:10	O 3-6 Efrem
		Makarov* (Russia)
		Post-cascade waves
		instead of
		temperature. Low
		atomic ordering
		temperatures at depth
		far beyond ion range
	12:30	Lunch
	14:00	Closing Ceremony, Young Researcher Award Ceremony
Chair:	16:00	Andre Anders
Jindrich		Lecture on the preparation of reports publication
Musil		
	18:00	Conference Banquet

Friday – August 30, 2019

09:00-19:00	Social program

Ion beam processing of materials, Monday - August 26, 2019

Session	Name	Poster Title
P 1-1	Alexey	Microstructure of titanium alloy modified by high-intensity
	Shevelev*	implantation of low- and medium-energy aluminum ions
P 1-2	Anna	Studies of the electrical properties of ion irradiation polymer materials
	Kosińska*	
P 1-3	Monica	Effect of ion irradiation on the structure of Inconel made by 3D
	Duchna*	printing method
P 1-4	Agata	Influence of ion irradiation on the nanomechanical and structural
	Zaborowska*	properties of thin alumina coatings
P 1-5	Boris	Interaction of plasma jets and ion beams of a plasma focus device with
	Lemeshko	the surface of chromium steel
P 1-6	Alexey	Structural-phase state of copper substrate under surface treatment by
	Podanev*	intense flux of Ti and Zr ions
P 1-7	Alexander	Pulsed ion beam induced changes in a topography of the surface layers
	Ligachev	of titanium
P 1-8	Olga Korneva	Modification of microstructure and properties of martensitic stainless
		steel by high-intensity implantation of nitrogen ions
P 1-9	Georgy	Temperature gradients in the irradiated targets during high-intensity
	Modebadze*	implantation and their influence on ion-modified layer properties
P 1-10	Ľubomír	Pattern formation on metallic surfaces induced by plasma immersion
	Gabriš*	ion implantation
P 1-11	Giovanni	Effect of He ⁺ irradiation of Ti ₂ InC at different ion beam fluences
	Ceccio*	
P 1-12	Yan Sha	Experimental and numerical simulations of cracking behaviors on
		tungsten under high intense pulsed ion beam irradiation
P 1-13	Pavol Noga	Ion beam synthesis of AuAg@Ag core/shell bimetallic nanoparticles in
		TiN
P 1-14	Vladislav	Combined method of cutting tool treatment
	Tarbokov	
P 1-15	Shijian Zhang	Defects formation and evolution on ceramics irradiated by intense
		pulsed ion beams
P 1-16	Olesya Laput*	Zn, Mg, Ag ion implantation of polylactic acid
P 1-17	Yurii Ivanov	Comprehensive electron-ion-plasma modification of Al-Si alloy
		surface
P 1-18	Vladimir	Restoration of ductility of cold-deformed aluminum alloys by short-
	Ovchinnikov	term irradiation with accelerated Ar ⁺ ions
P 1-19	Valeria	Surface modification of ZrO ₂ -3Y ₂ O ₃ ceramics with high-intensity
	Kostenko*	pulsed N ₂ ⁺ ion beams
P 1-20	Ivan Zhidkov	XPS characterization of surface layers of stainless steel nitrided in
		electron beam plasma
P 1-21	Yulia	Structure and phase states modification of Al-Si alloy by the ion-
	Rubannikova*	plasma jet and pulsed electron beam treated
P 1-22	Wolfgang	Retardation of corrosion induced hydrogen embrittlement of tantalum
	Ensinger	by ion beam surface alloying with platinum
P 1-23	Umirzakov	Influence of the formation nickel silicide on resistivity of silicon
	Baltakhadja	
P 1-24	Gwomei Wu	Study of fabrication and characterization of title: high power 850 nm
D 1 25	T. 1	vertical-cavity surface-emitting laser arrays
P 1-25	Tazhen	Interaction of pulsed plasma with the surface of the material and dust
	Aigerim	formation

P 1-26	Marat	Pulsed ion beam irradiation of silver nanowire networks for use in
	Kaikanov*	transparent conductive films
P 1-27	Abdirash	High energy ionoluminescence of Al ₂ O ₃ and LiF: time resolved studies
	Akilbekov	
P 1-28	Juraj Halanda	High fluence Fe implanted polyethylene surface characterization
P 1-29	Egor	The effect of plasma Ar and Xe on surface roughness of fuel cladding
	Korenevski	tube
P 1-30	Alexey	Nanodiamond luminescence in hemispherical Fabry-Perot microcavity
	Romshin	fabricated by FIB
P 1-31	Geliy	Craters on the surface metal after HPIB of carbon ions
	Potemkin	
P 1-32	Valentina	Modification of titanium nickelide by irradiation with heavy ions of
	Poltavtseva	inert gases
P 1-33	Denis Sivin	High-intensity implantation of metal ions in conditions of minimizing
		ion sputtering of the material surface
P 1-34	Marat	Modification of sputter deposited silver nanostructures with thermal
	Kaikanov*	annealing vs pulsed ion beam irradiation
P 1-35	Artem	Study of the effect of various types of irradiation on ceramic materials
	Kozlovskiy*	
P 1-36	Artem	The use of pulsed beams for increasing radiation resistance of AlN
	Kozlovskiy*	ceramics
P 1-37	Zaki Adam	Diffusion behaviour of selenium implanted into polycrystalline SiC
	Yousif	
	Abdalla	
P 1-38	Mikhail	Comparison of the optical properties degradation of oxide micro- and
	Mikhailov*	nanopowders irradiated by 100 keV protons
P 1-39	Alexey	Effect of proton irradiation on the optical properties of coating based
	Lapin*	on ZnO powder and liquid K ₂ SiO ₃
P 1-40	Vitaliy	Influence of high-intense ion pulses on tungsten surface erosion
	Shymanski*	-

Ion-assisted coating deposition, Tuesday - August 27, 2019

Session	Name	Poster Title
P 2-1	Maxim	The deposition of Cu-films in a planar magnetron sputtering system at
	Shandrikov	ultra-low operating pressure
P 2-2	Alexander	Direct current arc plasma synthesis of superdisperced powder materials
	Pak*	in «tungsten-carbon» system
P 2-3	Anatolii	Modification with an intense pulsed electron beam of the structure and
	Klopotov	properties of a powder coating of the Ni-Cr-B-Si system, plasma-
		sprayed on steel
P 2-4	Alisa	Features of multilayer coatings on the basis of Zr-Y-O/Si-Al-N system
	Nikonenko*	
P 2-5	Takaomi	Development of nitrogen ion beam sputtering and mixing deposition
	Matsutani	method for nitride film formation
P 2-6	Nikita	Deposition of gradient Zr-Nb-N coatings by vacuum-arc method with
	Prokopenko*	ion-plasma assistance
P 2-7	Galina	Controlling the properties of metal films deposited using magnetron
	Bleykher	sputtering systems with evaporative targets
P 2-8	Dmitry	Study of magnetron-sputtered coatings on ion-modified surface of
	Safonov*	alloy E110
P 2-9	Rustem	Properties of intermetallic-based Ti-Al coatings deposited on the
	Nagimov*	ultrafine grained martensitic steel
P 2-10	Alexey	Surface modification of E110 alloy by high-intensity low ion energy
	Shevelev*	Cr implantation
P 2-11	Vladimir	Hard and wear-resistant niobium carbide layered coatings on tools by
	Uglov	niobium ion bombardment and cathodic vacuum arc deposition

Basic mechanisms, theory and fundamental, Wednesday - August 28, 2019

Session	Name	Poster Title
P 3-1	Haocheng	Radiation tolerance of La-doped nanocrystalline steel under heavy-ion
	Liu*	irradiation at different temperatures
P 3-2	Haowen	The influence to crater formation by inclusions on metal surface during
	Zhong	IPIB irradiation process
P 3-3	Jin-Xia	The odd-even effect of fragmentation cross sections for 36Ar and 40Ar
	Cheng	
P 3-4	Koumei	Deposition of diamond-like carbon films on insulating substrates
	Baba	
P 3-5	Alisa	Influence of implantation by ions of aluminium on change of size of
	Nikonenko*	grain of UFG-titanium
P 3-6	Yu Xiao*	The ablation of metals and plastics by intense pulsed ion beam
P 3-7	Guoying	Effect of vacancy on thermal conduction during energetic ions
	Liang	irradiation: a molecular dynamics study
P 3-8	Maria	Thermal-diffusion model of ion implantation with Soret and Dufour
	Chepak-	effects
	Gisbrecht	
P 3-9	Noriaki	Electrical resistivity modification of graphene layers by low energy ion
	Matsunami*	irradiation
P 3-10	Nikolay	Nonideality factor in entropy-multifractal analysis of surfaces
	Makarevich	
P 3-11	Ivan	Interfacial reactions in Al ₂ O ₃ / Cr ₂ O ₃ interfaces obtained by pulsed
	Zhidkov	magnetron sputtering
P 3-12	Ivan	Electronic structure of ion-implanted 3d impurities in a topological
	Zhidkov	insulator Bi ₂ Te ₃

Defect engineering, nano-science and technology, Wednesday - August 28, 2019

P 4-1 Nikolay Cherenda plasma flows impact P 4-2 Setsuo Nakao Effect of hydrogen content on water wettability of diamond-like carbon films prepared by plasma-based ion implantation and deposition P 4-3 Phan Luong Tuan Investigations of chemical composition and thickness of oxide layers deposited on Si GaAs implanted with Xe ions P 4-4 Elke Wendler Radiation tolerance of nanostructured TiAlN coatings under Ar⁺ ion irradiation P 4-5 Alexander Admittance studies of modification of HgCdTe surface properties with ion implantation and thermal annealing P 4-6 Alexander Korotaev with ion implantation and thermal annealing P 4-7 Alexander Kinetics of formation of nanostructures by Frank-van der Merwe, Volmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander The relaxation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He²+ ion beam and short-pulsed 200 keV C⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C⁺ ion beam and 350 keV He²+ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-13 Arseny Ion beam stimulated defects in transparent MgAl₂O₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev P 4-16 Alma Structure and properties of CdTe nanocrystals created in SiO₂/Si arck templates track templates carchivate and properties of CdTe nanocrystals created in SiO₂/Si track templates track templates track templates track templates carchivate and properties of CdTe nanocrystals created in SiO₂/Si	Session	Name	Poster Title
P 4-2 Setsuo Nakao Effect of hydrogen content on water wettability of diamond-like carbon films prepared by plasma-based ion implantation and deposition P 4-3 Phan Luong Investigations of chemical composition and thickness of oxide layers deposited on Si GaAs implanted with Xe ions P 4-4 Elke Wendler Radiation tolerance of nanostructured TiAlN coatings under Ar ⁺ ion irradiation P 4-5 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Korotaev Wolmer-Weber and Stranski-Krastanow growth modes P 4-7 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander The relaxation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C* ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-1	•	
carbon films prepared by plasma-based ion implantation and deposition P 4-3 Phan Luong Tuan deposited on Si GaAs implanted with Xe ions P 4-4 Elke Wendler Radiation tolerance of nanostructured TiAlN coatings under Ar ⁺ ion irradiation P 4-5 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Hall effect studies of modification of HgCdTe surface properties with ion implantation and thermal annealing P 4-7 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander Korotaev The relaxation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion Pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the El IO zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			1
P 4-3 Phan Luong Tuan deposition P 4-4 Elke Wendler P 4-5 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Korotaev din implantation and thermal annealing P 4-7 Alexander Korotaev din implantation and thermal annealing P 4-8 Alexander Korotaev din implantation and thermal annealing P 4-7 Alexander Korotaev din implantation and thermal annealing P 4-8 Alexander Korotaev din implantation and thermal annealing P 4-8 Alexander Korotaev din implantation of nanostructures by Frank-van der Merwe, Korotaev din implantation of nanostructures by Frank-van der Merwe, Korotaev din implantation of nanostructures by Frank-van der Merwe, Korotaev din implantation of nanostructures by Frank-van der Merwe, Korotaev din implantation of nanostructures by Frank-van der Merwe, Korotaev din implantation of nanostructures by Frank-van der Merwe, Korotaev din implantation of nanostructures by Frank-van der Merwe, Volmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander Korotaev din implantation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He²+ ion beam and short-pulsed 200 keV C⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C⁺ ion beam and 350 keV He²+ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl₂O₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments D auletbekova	P 4-2	Setsuo Nakao	·
P 4-3 Phan Luong Tuan deposited on Si GaAs implanted with Xe ions P 4-4 Elke Wendler Radiation tolerance of nanostructured TiAlN coatings under Ar* ion irradiation P 4-5 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Korotaev With ion implantation and thermal annealing P 4-7 Alexander Korotaev Volmer–Weber and Stranski–Krastanow growth modes P 4-8 Alexander Korotaev Volmer–Weber and Stranski–Krastanow growth modes P 4-8 Alexander Korotaev Volmer–Weber and Stranski–Krastanow growth modes P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of \$28 MeV He ²⁺ ion beam and \$350 keV He ²⁺ ion pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			carbon films prepared by plasma-based ion implantation and
P 4-4 Elke Wendler Radiation tolerance of nanostructured TiAIN coatings under Ar* ion irradiation P 4-5 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Korotaev With ion implantation and thermal annealing P 4-7 Alexander Korotaev Wolmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-9 Sergey Effect of 28 MeV He²+ ion beam and short-pulsed 200 keV C⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			
P 4-5 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Korotaev with ion implantation and thermal annealing P 4-7 Alexander Korotaev ion implantation and thermal annealing P 4-7 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion Pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of 5 hort-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Multilayer Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-3	Phan Luong	Investigations of chemical composition and thickness of oxide layers
P 4-5 Alexander Korotaev Admittance studies of modification of HgCdTe surface properties with ion implantation and thermal annealing			
P 4-6 Alexander Korotaev with ion implantation and thermal annealing P 4-6 Alexander Korotaev with ion implantation and thermal annealing P 4-7 Alexander Korotaev ion implantation and thermal annealing P 4-7 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-8 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Dahumaev Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-4	Elke Wendler	=
P 4-6 Alexander Korotaev Hall effect studies of modification of HgCdTe surface properties with ion implantation and thermal annealing			
P 4-6 Alexander Korotaev Hall effect studies of modification of HgCdTe surface properties with ion implantation and thermal annealing P 4-7 Alexander Korotaev Kinetics of formation of nanostructures by Frank—van der Merwe, Volmer—Weber and Stranski—Krastanow growth modes P 4-8 Alexander Korotaev The relaxation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion Pavlov* Deam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-5		
Rorotaev Ion implantation and thermal annealing P 4-7 Alexander Kinetics of formation of nanostructures by Frank—van der Merwe, Volmer—Weber and Stranski—Krastanow growth modes P 4-8 Alexander Korotaev The relaxation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			• •
P 4-7 Alexander Korotaev Volmer-Weber and Stranski-Krastanow growth modes	P 4-6		
P 4-8 Alexander Korotaev The relaxation of electrophysical properties HgCdTe epitaxial films affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air			<u> </u>
P 4-8 Alexander Korotaev	P 4-7		
Rorotaev affected by plasma of high frequency nanosecond volume discharge in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion Pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion Pavlov* beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			
in atmospheric-pressure air P 4-9 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion Pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion Pavlov* beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-8	Alexander	
P 4-19 Sergey Effect of 28 MeV He ²⁺ ion beam and short-pulsed 200 keV C ⁺ ion beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		Korotaev	
Pavlov* beam irradiation on optical properties of multilayer Al-Si-N coatings P 4-10 Sergey Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Chao Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			in atmospheric-pressure air
P 4-10 Sergey Pavlov* Effect of short-pulsed 200 keV C ⁺ ion beam and 350 keV He ²⁺ ion beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-9	Sergey	
Pavlov* beam irradiation on optical properties of Al-Si-N coatings with a various Si content P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		Pavlov*	
P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: Dauletbekova experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-10	~ .	•
P 4-11 Jerzy Zuk Doping and the band gap engineering in group IV alloys using ion implantation and flash lamp annealing P 4-12 Der-Sheng Chao Chao Chao Defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Dzhumaev Dzhumaev Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: Dauletbekova Dauletbekova P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		Pavlov*	
implantation and flash lamp annealing P 4-12 Der-Sheng Crystallographic orientation dependence of blistering kinetics and defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			
P 4-12 Der-Sheng Chao Chao Chao Chao Chao Chao Chao Chao	P 4-11	Jerzy Zuk	
Chao defect evolution in silicon implanted by hydrogen ions P 4-13 Arseny Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Dzhumaev Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si			<u> </u>
P 4-13 Arseny Kiryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Dzhumaev Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-12	_	• • •
Riryakov* P 4-14 Hana Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		Chao	
P 4-14 Hana Faitová* Focused-ion-beam controlled nucleation and growth of ZnO nanorod Faitová* P 4-15 Pavel Dzhumaev Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe₂O₅ nanocrystals in a-SiO₂/Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO₂/Si	P 4-13	•	Ion beam stimulated defects in transparent MgAl ₂ O ₄ ceramic
P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium Dzhumaev alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: Dauletbekova experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		•	
P 4-15 Pavel Magnetron deposition of multilayer coatings on the E110 zirconium alloy cladding tube segments P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-14		Focused-ion-beam controlled nucleation and growth of ZnO nanorods
P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: Dauletbekova experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		Faitová*	
P 4-16 Alma Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template: Dauletbekova experimental studies and theoretical calculations P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-15		• •
P 4-17 Alma experimental studies and theoretical calculations Structure and properties of CdTe nanocrystals created in SiO ₂ /Si		Dzhumaev	<u> </u>
P 4-17 Alma Structure and properties of CdTe nanocrystals created in SiO ₂ /Si	P 4-16	Alma	Synthesis of ZnSe ₂ O ₅ nanocrystals in a-SiO ₂ /Si-n track template:
<u> </u>		Dauletbekova	experimental studies and theoretical calculations
Dauletbekova track templates	P 4-17		* *
		Dauletbekova	track templates

New accelerator systems and tools for materials research, Wednesday - August 28, 2019

Session	Name	Poster Title
P 5-1	Vasily	
	Gushenets	Ring-shaped ion sources based on closed drift anode layer thruster
P 5-2	Maxim	Source of high-intensity ultra-low-energy ion flow and bulk gaseous
	Shandrikov	plasma for large-area surface modification
P 5-3		Investigation of magnetically insulated diode for intense pulsed ion
	Yu Xiao*	beam generation for materials research
P 5-4		Application of silicone based polymer modified by low energy
		nitrogen ion beam to diaphragm for environmental-cell transmission
	Yuki Tai*	electron microscope
P 5-5	Vitaly	Aluminum HIPIB production in ion diode with self-magnetic
	Shamanin*	isolation
P 5-6	Pavlov	High-current pulsed induction plasma source for generation of high
	Sergey*	intensity ion beams of various gases
P 5-7	_	Generation of beams of multiply charged heavy metal ions of
	Efim Oks	bismuth up to 19 ⁺ in a pulsed high current vacuum arc ion source

Poster Session 6

Biomedical and industrial applications, Wednesday - August 28, 2019

Session	Name	Poster Title
P 6-1	Konstantin	Atmospheric pressure plasma jet application for magnesium and
	Savkin	zinc oxides generation
P 6-2		A theoretical model for predicting and optimizing in vitro screening
	Wenzong Ma	of potential targeted alpha-particle therapy drugs
P 6-3		Diamond film etching by low energy large aperture ion beams for
	Alexey Remnev	cutting tools reconditioning
P 6-4	Vasily	Ion beam assisted deposition of rare earth metals and platinum for
	Poplavsky	obtaining of catalytic layers
P 6-5	Vladislav	Titanium surface roughness modification using ion beam and
	Tarbokov	mechanical method